Charge movement in gating-locked HCN channels reveals weak coupling of voltage sensors and gate

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Charge movement in gating-locked HCN channels reveals weak coupling of voltage sensors and gate

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HCN (hyperpolarization-activated cyclic nucleotide gated) pacemaker channels have an architecture similar to that of voltage-gated K+ channels, but they open with the opposite voltage dependence. HCN channels use essentially the same positively charged voltage sensors and intracellular activation gates as K+ channels, but apparently these two components are coupled differently. In this study, we examine the energetics of coupling between the voltage sensor and the pore by using cysteine mutant channels for which low concentrations of Cd²⁺ ions freeze the open–closed gating machinery but still allow the sensors to move. We were able to lock mutant channels either into open or into closed states by the application of Cd²⁺ and measure the effect on voltage sensor movement. Cd²⁺ did not immobilize the gating charge, as expected for strict coupling, but rather it produced shifts in the voltage dependence of voltage sensor charge movement, consistent with its effect of confining transitions to either closed or open states. From the magnitude of the Cd²⁺-induced shifts, we estimate that each voltage sensor produces a roughly three- to sevenfold effect on the open–closed equilibrium, corresponding to a coupling energy of ~1.3–2 kT per sensor. Such coupling is not only opposite in sign to the coupling in K+ channels, but also much weaker.

INTRODUCTION

HCN (hyperpolarization-activated cyclic nucleotide gated) channels are widely expressed throughout the heart and the nervous system, including the sino-atrial node, hippocampal pyramidal cells, and photoreceptor cells (Kaupp and Seifert, 2001). They play a key role in regulating rhythmic activity of cardiac pacemaker cells and spontaneously firing neurons (McCormick and Pape, 1990; DiFrancesco, 1993). They are also involved in various neuronal processes, including dendritic integration (Magee, 1999), synaptic transmission (Beaumont et al., 2002), and the temporal processing of visual signals in the retina (Demontis et al., 1999). Four mammalian HCN channel subunits (mHCN 1–4) have been found so far (Santoro et al., 1997, 1998; Ludwig et al., 1998; Ishii et al., 1999), and homologues have been cloned from several invertebrates such as sea urchins (SPH or sea urchin HCN) [spHCN]; Gauss et al., 1998) and bacteria (Sesti et al., 2003). The functional loss of HCN channels leads to defects in the learning of motor tasks or to serious cardiovascular conditions such as arrhythmia, congestive heart failure, or myocardial infarction (Biel et al., 2009).

HCN channels are structurally similar to voltage-gated K+ channels in that they have six transmembrane segments (S1–S6) that include a putative voltage sensor (S4) and a pore region between S5 and S6 (Kaupp and Seifert, 2001). Moreover, the S4 movement in the spHCN channel is similar to that in voltage-gated Kv channels such as Shaker channels (Männikkö et al., 2002). However, unlike typical voltage-gated K+ channels that are gated by depolarization, HCN channels are activated by hyperpolarization. Using the same intracellular gate, inward movement of the voltage sensor upon hyperpolarization is coupled to channel opening in HCN channels (Männikkö et al., 2002; Rothberg et al., 2002). The coupling mechanism in spHCN channels is also peculiar in that the inward movement of the voltage sensors may be loosely coupled to channel opening when cAMP is absent, allowing the gates to slip back to the closed state (inactivation, desensitization to voltage, or loss of coupling; Shin et al., 2004). The binding of cAMP to the C-terminal cyclic nucleotide-binding domains can relieve this fast inactivation process and increase the maximum open probability.

The domains of HCN channels that are important for voltage gating have been identified from previous studies (Chen et al., 2001; Männikkö et al., 2002; Bell et al., 2004). Alanine-scanning mutagenesis indicates the S4–S5 linker is involved in the coupling between S4 movement and channel gating (Chen et al., 2001), but the details of the mechanism that couples the voltage sensors to gating are still not fully understood. Several kinetic models have been suggested to explain the molecular basis of voltage-dependent gating in HCN channels (Altomare et al., 2001; Wang et al., 2002; Shin et al., 2004; Männikkö et al., 2005). However, information

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about the energetics and mechanism of voltage-gated opening in HCN channels is still sparse.

Previous studies found that cysteine substitutions at positions H462 and L466 in the S6 region of the spHCN channel produce a “locked-open” phenotype of the channel when Cd²⁺ is applied to the cytosolic side of the channels, apparently because the Cd²⁺ ion can form an energetically favorable bridge between the two cysteines (Rothberg et al., 2003). A comparable “locked-closed” phenotype with Cd²⁺ application is seen for the Q468C mutant (studied in the presence of an H462Y mutation to prevent a competing locked-open effect; Rothberg et al., 2003). Here, we exploited the effects of Cd²⁺ on these mutants to study the coupling energetics between voltage sensor and channel gating by measuring gating currents of the locked-open and locked-closed mutants expressed in Xenopus oocytes. We found that Cd²⁺ shifted the gating charge-voltage (QV) relationship to more positive potentials for a locked-open mutant (462C466C), whereas it shifted the QV relationship to more negative potentials for a locked-closed mutant (462Y468C). We used these data together with a simple allosteric model for coupling between the voltage sensors and the opening/closing transitions to describe the coupling energetics of these hyperpolarization-activated channels.

MATERIALS AND METHODS

Expression of recombinant HCN channels
cDNA for wild-type spHCN channels was transcribed in vitro using T7 RNA polymerase (mMessage Machine; Invitrogen). The final cRNA was resuspended in RNase-free water to a final concentration of 1 μg/μl and kept at −80°C. Defolliculated Xenopus oocytes were prepared and injected with ~30–50 nl cRNA. Injected oocytes were incubated at 16–20°C in ND96 (96 mM NaCl, 5 mM KCl, 1 mM HEPES, pH 7.6) supplemented with 100 μM cAMP, which saturates the cAMP binding site and eliminates the inactivation process seen for spHCN channels in the absence of cAMP.

Methods for rapid perfusion were performed as described previously (Liu et al., 1997). The solution exchange time (~1 ms) was determined at the end of experiments by examining the current response for an open patch pipette during a switch to a 160 mM K⁺ solution.

Data analysis
Conductance-voltage (G-V) curves were obtained from the amplitude of the tail currents at 60 mV. The conductance-voltage (G-V) and QV curves were fitted with Origin 7 (OriginLab) using the Levenberg-Marquardt algorithm and the instrumental weighting method. A Boltzmann equation (\(Q = \frac{1}{1 + \exp(-\frac{V - V_{\text{1/2}}}{kT})}\)) was used to fit the QV curve to estimate the \(V_{\text{1/2}}\) (the voltage at which half of the charge is transferred) and \(z\) (the valence of the transferred charge). Linear capacitive currents were subtracted by a −P/4 protocol from a secondary holding potential of 60 mV. Gating charge moved during each test hyperpolarization (Q(on)) was quantified by integrating the first 50 ms of gating currents during hyperpolarization (Q(on)) or depolarization (Q(off)), after defining the baseline to be the steady-state current level for at least the last 5 ms.

For the fitting of QV and G-V curves using a 10-state MWC (Monod-Wyman-Changeux) allosteric model (see Fig. 1 A), the following equilibrium equations were used:

\[
\frac{Q}{Q_{\text{max}}} = \frac{f(1 + f)^{3} + Lf}{1 + f (1 + f)^{3}}\]

\[
\frac{P}{P_{\text{max}}} = \frac{f(1 + f)^{3}}{1 + f (1 + f)^{3}}.
\]

where \(L\) is the equilibrium constant for the CO transition when the voltage sensor is in the deactivated state, and \(f = f_{0} \exp(-zV/kT)\), where \(f_{0}\) is the equilibrium constant for the activation of a single voltage sensor when the channel gate is closed. \(\theta\) is the coupling factor between voltage sensor activation and channel gating, and \(z\) is the effective gating charge for a single sensor. Model parameters were estimated from a simultaneous fit to the QV curves (with and without Cd²⁺) and the G-V curve (obtained from rapid perfusion, as in Fig. 2). Parameter error estimates were those obtained from the nonlinear fit in Origin 7, using nominal instrumental errors of 0.05 (on a scale from zero to one) rather than the observed errors in order to avoid distortions caused by the low errors for points near zero and one produced by the normalization procedure.

Online supplemental material
Fig S1 shows QV curves for wild-type spHCN channels in the absence and presence of intracellular Cd²⁺, illustrating the lack of effect. Fig S2 shows the G-V relations for wild-type spHCN, 462C466C, and 462Y468C, measured with activating voltage steps applied in symmetrical NMG-containing solutions, but with tail currents measured immediately after rapid perfusion of K-containing solution to the exposed (intracellular) face of the patch. Online supplemental material is available at http://www.jgp.org/cgi/content/full/jgp.201210850/DC1.

RESULTS
Approaches to estimating the coupling between voltage sensor activation and channel opening
The relationship between voltage sensor activation and channel opening of the spHCN channel can be illustrated
by a gating scheme based on a standard MWC allosteric model, as previously used for voltage-gated channels such as BK Ca\(^{2+}\)-activated K\(^{+}\) channels (Monod et al., 1965; Cox et al., 1997). Because spHCN channels contain four voltage sensors (Biel et al., 2009), the model results in a scheme with 10 states, comprising open and closed states with varying numbers (zero to four) of activated voltage sensors (Fig. 1 A). According to this voltage-dependent MWC scheme (Fig. 1 A), the closed (C)–open (O) equilibrium constant, which governs transitions between a closed state at the top of the diagram and an open state at the bottom, will vary with the number of activated voltage sensors (left-right transitions): when voltage sensors are in the deactivated state, gating equilibrium is biased toward the closed state, whereas when voltage sensors are in the activated state, the gating equilibrium is biased toward the open state. It necessarily follows from the energetic system of the channel that the state of the gate (open or closed) will affect the tendency of voltage sensors to activate; in open channels, voltage

![Diagram](image)

Figure 1. Equilibrium models of coupling between voltage sensors and gating. (A) Standard allosteric model for coupling of four voltage sensors to simple channel opening. (B) Simplified version of A, with equilibrium constants summarized for fully activated (A) and deactivated (D) voltage sensors and open (O) and closed (C) channels. The diagram is heuristic and does not indicate a direct connection between \(C_0\) and \(C_1\) or between \(O_0\) and \(O_1\); the overall equilibrium constants shown between these extreme states are simply equal to the product of the intervening equilibrium constants. (C) Two approaches to estimating the coupling constant \(\theta\).

sensors can activate more easily (in the diagram, this corresponds to horizontal state changes). This allosteric linkage between channel opening and voltage activation, quantified by coupling factor \(\theta\), accounts for the ability of voltage sensors to affect open probability or vice versa.

The focus of our study is to measure this coupling factor, which reveals the energetics of coupling between the voltage sensor and the channel gating in spHCN channels. Conceptually, the coupling factor \(\theta\) describes the ratio of equilibrium constants, either for gating in various states of the sensor or for the sensor in various gating states. A conceptually simpler diagram can be used to emphasize the energetics between the limiting (fully activated or fully deactivated, open or closed) states of the channel (Fig. 1 B). In the context of this simplified diagram, we also show an alternative (but equivalent) description of the equilibrium constants: \(K_{\text{gate(D)}}\) and \(K_{\text{gate(A)}}\) are the equilibrium constants for the far left and far right vertical transitions, and they describe the open–closed equilibrium constants for fully deactivated versus activated sensors. \(K_{\text{sens(C)}}\) and \(K_{\text{sens(O)}}\) are the equilibrium constants for the activation of a single voltage sensor when the channel gate is either closed or open. In this framework, there are two ways to measure the coupling factor \(\theta\) (Fig. 1 C): either by measuring the ratio of closed–open equilibrium constants for the activated and deactivated positions of the voltage sensors or the ratio of the equilibrium constants for gating charge movement with the channel in the open state versus in the closed state (Fig. 1 C).

The first way of calculating \(\theta\), using the open–closed equilibrium constants at extreme voltages, is error prone: the equilibrium constants are hard to calculate precisely when open probability is close to 0 or close to 1. Although single-channel currents through spHCN channels have been recorded successfully in a previous study (Dekker and Yellen, 2006), it is difficult to measure the open probabilities at extreme voltage conditions using single-channel recordings. Even if successful, this approach would be likely to give an erroneous estimate of the magnitude of the closed–open equilibrium constants that are coupled to the sensors. At maximum activating voltages, ion channels rarely have an open probability of 1 because of fast flicker gating and ionic block of the channel. At deactivating voltages, spHCN channels exhibit a voltage-independent opening process (Proenza and Yellen, 2006) that would obscure the limiting voltage-dependent equilibrium constant for gating.

These problems suggest the use of the alternative way of calculating \(\theta\), by measuring the voltage sensor equilibrium when the channel is always closed or always open. Because this ratio is \(\theta\) rather than \(\theta^4\), the expected changes are less extreme, and because the equilibrium is measured by varying voltages and examining the midpoints, the changes are more measurable. The locked-open and locked-closed effects of Cd\(^{2+}\) that we have
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Effects of Cd$^{2+}$ on spHCN 462C466C and 462Y468C mutants (A and B). Representative recordings from inside-out patches excised from *Xenopus* oocytes expressing either spHCN 462C466C (A) or spHCN 462Y468C (B) before and during the application of 130 nM free Cd$^{2+}$. Channels were held at 10 mV, and currents were elicited by a step to $-120$ mA or $-130$ mV (B), followed by a step to 60 mV. Currents were not leak subtracted. (C and D) To test whether the expressed channels still represent mutant phenotype in the condition of measuring the gating current (160 mM NMDA + 160 mM MeSO$_3$ for pipette and bath), a 160 mM K$^+$ solution was applied rapidly to inside-out patches expressing spHCN 462C466C (C) or spHCN 462Y468C (D). The black trace in C indicates the response with NMDA on both sides and 130 nM free Cd$^{2+}$, whereas the red trace shows the current response with the switch to intracellular K$^+$ immediately before the voltage step from $-120$ to 60 mV; the sustained outward current indicates the locked-open effect. The gray arrow in C indicates the time when the solenoid was engaged; the solution switch at the patch occurred $\sim$50 ms later, and the actual switching speed was <1 ms. (D) The black trace shows a normal tail current for the locked-closed mutant in the absence of Cd$^{2+}$ when intracellular K$^+$ was applied immediately before the voltage step from $-120$ to 60 mV. The red trace again shows the response with fast perfusion of K$^+$ solution, but in the constant presence of 130 nM free Cd$^{2+}$, and the blue trace indicates the gating current alone (no K$^+$ perfusion) with 130 nM free Cd$^{2+}$ present.

Cd$^{2+}$-induced effects on mutant gating persist under gating current conditions

We have previously found that spHCN channels with cysteine substitutions at positions 462 and 466 in the S6 region can be locked open by low concentrations of Cd$^{2+}$ applied to the cytosolic side of the channels (Rothberg et al., 2003). As shown in Fig. 2 A, the normal closing of the channels at positive voltages (black trace), apparent as a time-dependent tail current, is nearly abolished with the application of Cd$^{2+}$ (red trace); the lock-open effect is also apparent by the large inward current immediately after the hyperpolarizing step. In contrast, channels with 462Y468C mutations in S6 exhibit a locked-closed effect with 130 nM free Cd$^{2+}$, which is apparent as an extreme slowing of the activation at negative voltages (Fig. 2 B, red trace), with the degree of slowing dependent on [Cd$^{2+}$] (Rothberg et al., 2003). Because the Cd$^{2+}$ binding is reversible, the locked-closed effect is not permanent—the small fraction of channels without Cd$^{2+}$ bound will open (and no longer bind Cd$^{2+}$ because of movement of the cysteines); this results in a very slow increase in current over time during hyperpolarization (Rothberg et al., 2003).

Before we tested the effect of Cd$^{2+}$ on the gating current in these mutants (462C466C and 462Y468C), we examined whether the mutants still retained their phenotypic characteristics of either locked open or locked closed under the very different ionic conditions used for measuring gating current. We typically measured gating currents in inside-out patches under conditions...
In which no ionic current flows through the channel by using nonconducting NMDG-methanesulfonate instead of K+. To test the actual state of the channel gates during the gating current measurement, we quickly changed the solution from nonconducting conditions (i.e., NMDG-methanesulfonate solution) to ionic current conditions (i.e., 160 mM K+) using a rapid perfusion system. These experiments were performed in the constant presence of a saturating concentration of Cd²⁺ (130 nM free Cd²⁺).

In gating current conditions with no K⁺ present, we held the membrane voltage at 60 mV, applied an opening pulse to −120 mV, and then depolarized back to 60 mV. The return of voltage sensors upon the final depolarization (seen from the OFF gating current, Iᵥ,OFF) of 462C466C was rapid (Fig. 2 C, black trace). When 160 mM K⁺ was applied rapidly just before the depolarization to 60 mV, the subsequent ionic tail current showed the typical locked-open phenotype of extremely slow and incomplete deactivation, as shown in Fig. 2 C (red trace). This result shows that channels were open and stabilized by Cd²⁺ even under gating current conditions, before the rapid reapplication of K⁺. The 462Y468C mutant also showed its characteristic (but opposite) behavior in Cd²⁺: the patch was switched rapidly into K⁺-containing solution at the end of the activating pulse, and the subsequent depolarizing pulse showed no ionic tail current, consistent with Cd²⁺ maintaining the channels in a closed state even during the activating voltage in nonconducting conditions (Fig. 2 D).

Locking channels open makes it easier to activate their voltage sensors

To elucidate the energetic contribution of voltage sensor activation to channel gating, we measured how locking channels open with Cd²⁺ affected the voltage dependence of gating currents. We first measured control gating currents in wild-type spHCN channels. Cd²⁺ application to the cytosolic side did not change the gating charge movement of the wild-type channels significantly compared with the absence of Cd²⁺ (Fig. S1), as previously seen for G-V curves of wild-type spHCN (Rothberg et al., 2002).

We next tested for changes in gating charge movement when the 462C466C mutant channel was locked open by Cd²⁺ (Fig. 3). Application of Cd²⁺ to this locked-open mutant right shifted the Q-V curve by 20 mV, indicating that locking the gate in the open state favors the activated state of the voltage sensors but does not immobilize them as seen when Shaker channels are locked open by N-type inactivation (Bezanilla et al., 1991). Because Cd²⁺ locks most of the channel gates in the open state, the OFF gating current represents a relatively pure measurement of Kᵥ₉₅(0), the voltage-dependent equilibrium constant for voltage sensor movement in the open channel, as diagrammed in Fig. 3 A. The Qᵥ₉₅-V shift to more positive potentials with Cd²⁺ in the locked-open mutant (Fig. 3 E) implies that the movement of voltage sensors while the channels are fixed in the open state is more favorable compared with the closed state (or, rather, compared with the mixture of closed- and open-state charge movements obtained in the absence of Cd²⁺). A similar shift was seen for the OFF gating charge movement (Qᵥ₉₅-V; Fig. 3 D), and the magnitude of this shift provides information about the energetic coupling.

Locking channels closed makes it more difficult to activate their voltage sensors

For the 462Y468C locked-closed mutant, the channels can be held in the closed state by the application of Cd²⁺, as shown in Fig. 4 A. The Qᵥ₉₅-V in the presence of Cd²⁺ was negatively shifted (by approximately −20 mV) compared with the Q-V in the absence of Cd²⁺, indicating that stabilization of the closed state biases the voltage sensors toward the deactivated state, such that more hyperpolarization is required to activate them (Fig. 4 E). The Qᵥ₉₅-V curve was also left shifted by ~20 mV (Fig. 4 D). The maximal ON gating charge appeared to be reduced ~10% by Cd²⁺ application, but when we increased the time interval for measuring ON gating current from 100 to 300 ms, the total Qᵥ₉₅ with or without Cd²⁺ became indistinguishable (unpublished data); this suggests that the change in the apparent total Qᵥ₉₅ for the shorter pulse occurred only because ON gating charge becomes slower with the application of Cd²⁺. Cd²⁺ produced no change in the Q-V curve for control spHCN channels without the introduced cysteines (unpublished data), arguing that the changes were not caused by nonspecific effects of Cd²⁺ on the channel or the electric field.

Discussion

We have measured gating currents of two spHCN mutant channels (462C466C and 462Y468C), exploiting the effect of Cd²⁺ on these mutants to examine subsets of the voltage activation process in isolation. When we used Cd²⁺ to lock these channels in either the closed or the open state, we found that a voltage-dependent gating current (representing movement of the voltage sensors) could nevertheless be measured. Were the coupling between voltage sensors and gate very strict, as it is, for instance, in Shaker K⁺ channels, we would have expected immobilization of the gating charge when channels are locked open or closed. Instead, locking the 462C466C mutant channels open with Cd²⁺ caused charge movement to occur at more positive voltages (a shift of ~20 mV), consistent with an easier activation of the voltage sensors when the gate is in the open state. On the other hand, Cd²⁺ shifted the Q-V curves of the 462Y468C mutant to more negative voltages, consistent with more difficult activation of voltage sensors when the gate is closed.
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Ideally, we would want to measure the shift directly between the Q-V of fully closed channels and that of fully open channels, but these data were obtained from two different channel mutants. Although the G-V curves of wild type and the locked-closed mutant have similar $V_{1/2}$ values in the absence of Cd$^{2+}$, the G-V curves of the locked-open mutant were shifted more negative (Fig. S2), indicating that we cannot just directly compare the two Cd$^{2+}$-locked Q-V curves. Different parameters are needed to describe the gating behavior of the different mutants, but it is possible to model the relative effect of Cd$^{2+}$ within each individual channel gate. Ideally, we would want to measure the shift directly between the Q-V of fully closed channels and that of fully open channels, but these data were obtained from two different channel mutants. Although the G-V curves of wild type and the locked-closed mutant have similar $V_{1/2}$ values in the absence of Cd$^{2+}$, the G-V curves of the locked-open mutant were shifted more negative (Fig. S2), indicating that we cannot just directly compare the two Cd$^{2+}$-locked Q-V curves. Different parameters are needed to describe the gating behavior of the different mutants, but it is possible to model the relative effect of Cd$^{2+}$ within each individual channel gate.
be open only when all the voltage sensors are activated, we would not have been able to observe voltage sensor charge movement in the locked-open channels. Instead, it seems likely, as hypothesized previously (Bruening-Wright et al., 2007), that the coupling between the voltage sensor and channel opening is allosteric, so that each activated voltage sensor makes channel opening more favorable.

To estimate the allosteric coupling coefficient $\theta$, we fitted a general 10-state allosteric model of the voltage-dependent MWC scheme to our Q-V data as well as to G-V data on each mutant both with and without Cd$^{2+}$.

**Figure 4.** Gating current and Q-V relations for the spHCN 462Y468C mutant. (A) Schematic description of the locked-closed mutant. The state of the channel with Cd$^{2+}$ is shaded, whereas the control condition without Cd$^{2+}$ is in the dashed area. (B and C) Traces of gating current records for spHCN 462Y468C without (B) or with Cd$^{2+}$ (C), from the same patch. Holding potential was 10 mV, and test pulses were from -30 to -170 mV in 10-mV increments. A -P/4 protocol was used to subtract leak and linear capacitive currents. (D and E) Normalized Q-V relations for spHCN 462Y468C without (open squares) or with Cd$^{2+}$ (closed squares). Both $Q_{ON}$ (D) and $Q_{OFF}$ (E) were obtained by integrating components. Smooth curves are single Boltzmann fits to the data with these parameters as follows: $Q_{ON}$ control: $V_{1/2} = -116.4 \text{mV} \pm 8.4$, slope factor (e-fold) = 21.2 ± 4.7; 100 µM cAMP + 130 nM free Cd$^{2+}$: $V_{1/2} = -131.8 \pm 7.5 \text{mV}$, slope factor (e-fold) = 18.1 ± 0.9; $n$ = 5. $Q_{OFF}$ control: $V_{1/2} = -96.7 \pm 5.3 \text{mV}$, slope factor (e-fold) = 16.0 ± 1.9; Cd$^{2+}$: $V_{1/2} = -128.0 \pm 2.3 \text{mV}$, slope factor (e-fold) = 21.1 ± 2.0; $n$ = 7. Error bars represent SEM.

**mutant using only the assumption that Cd$^{2+}$ confines the conformational range of channel gating to open states (for the locked-open mutant) or to closed states (for the locked-closed mutant).**

**Fitting to a simple allosteric gating model reveals weak coupling between voltage sensor activation and channel opening**

What is the relationship between voltage sensors and opening of the channel gate in the spHCN channel? Our observations seem to rule out an obligatory coupling between the two; for instance, if the channel can be open only when all the voltage sensors are activated, we would not have been able to observe voltage sensor charge movement in the locked-open channels. Instead, it seems likely, as hypothesized previously (Bruening-Wright et al., 2007), that the coupling between the voltage sensor and channel opening is allosteric, so that each activated voltage sensor makes channel opening more favorable.

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control the equilibrium behavior of this model: $K_{\text{gate(D)}}$, the equilibrium constant between open and closed, when no voltage sensors are active; $K_{\text{sens(C)}}$, the equilibrium constant for voltage activation when the channel is closed; $z$, the gating charge associated with each voltage sensor’s movement; and $\gamma$, the coupling factor. A previous study showed that including cooperativity did not improve the fit (Bruening-Wright et al., 2007), so we did not include any cooperativity between voltage sensors.

The MWC model is too simple to account for some known peculiarities of HCN channel gating—hysteresis, inactivation, and possibly multiple transitions in each S4 segment—but our experiments were designed to minimize the influence of these complex gating features. Hysteresis of the spHCN channel is observed.

The 10-state allosteric model in the scheme (Fig. 1 A) is analogous to the models developed for BK channels (Horrigan et al., 1999) and KCNQ1 channels (Ma et al., 2011). Datasets for $Q_{\text{OFF}}$ (Fig. 3 A and Fig. 4 A) were used, and to minimize any difference caused by the unusual ionic conditions, the G-V curves were measured under practically the same condition as the gating current experiments: 160 mM NMDG-methanesulfonate solution was constantly perfused during the test pulses (from $-150$ to $-20$ mV in 10-mV increments), and 160 mM K$^+$ was applied to the inside-out patches of the channels just before the switch to 60 mV. The resultant ionic tail current was used to compile G-V curves (Fig. 5, A and B).

The 10-state MWC model was used to fit the experimental results. There are only four parameters that control the equilibrium behavior of this model: $K_{\text{gate(D)}}$, the equilibrium constant between open and closed, when no voltage sensors are active; $K_{\text{sens(C)}}$, the equilibrium constant for voltage activation when the channel is closed; $z$, the gating charge associated with each voltage sensor’s movement; and $\gamma$, the coupling factor. A previous study showed that including cooperativity did not improve the fit (Bruening-Wright et al., 2007), so we did not include any cooperativity between voltage sensors.

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and presence of Cd²⁺; the effect of Cd²⁺ in the model

gating parameters to describe the data in both the absence
details of the intervening steps.

Although the detailed shape (and the midpoint) of the
should be little affected by the multiple steps, so long as
state Q-V curves for voltage sensor activation, our data
clamp fluorometry experiments. By focusing on steady-
hysteresis. We also used a saturating concentration of
col such that we held at depolarized potentials and
the application of Cd²⁺, we designed the voltage proto-
require the observation of the shifts in Q-V curves by
with a depolarizing holding potential (Männikkö et al.,
stay at a hyperpolarizing holding potential compared
to other voltage-gated channels. Several
voltage sensor of
these values give an estimated coupling energy per
in terms of molecular free energy change (kT ln θ),
these channels.

The trapezoid method (Chowdhury and Chanda, 2012) was used to
calculate the Vmedian values from locked-open and locked-closed mutants,
and V1/2 values were calculated from a single Boltzmann fit.

For each mutant, we allowed a single set of MWC gat-
parameters for curve fitting for Fig. 5

We thank the members of the Yellen laboratory and Dr. Bruce
Bean for their advice and suggestions and thank Tatiana Abramson
for expert technical support.

This work was supported by a research grant (R01 HL070320)
from the National Heart, Lung, and Blood Institute (National
Institutes of Health) to G. Yellen.

Sharona E. Gordon served as editor.


